

Data sheet acquired from Harris Semiconductor SCHS056D – Revised August 2003

CMOS OR Gates

High-Voltage Types (20-Volt Rating)

CD4071B Quad 2-Input OR Gate CD4072B Dual 4-Input OR Gate CD4075B Triple 3-Input OR Gate

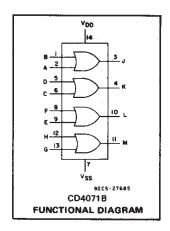
■ CD4071B, CD4072B, and CD4075B OR gates provide the system designer with direct implementation of the positive-logic OR function and supplement the existing family of CMOS gates.

The CD4071B, CD4072B, and CD4075B types are supplied in 14-lead hermetic dual-in-line ceramic packages (F3A suffix), 14-lead dual-in-line plastic packages (E suffix), 14-lead small-outline packages (M, MT, M96, and NSR suffixes), and 14-lead thin shrink small-outline packages (PW and PWR suffixes).

CD4071B, CD4072B, CD4075B Types

Features:

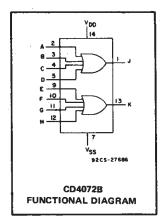
- Medium-Speed Operation-tp_{LH}, tp_{HL} = 60 ns (typ.) at V_{DD} = 10 V
- 100% tested for quiescent current at 20 V
- Maximum input current of 1 μA at 18 V over full package-temperature range; 100 nA at 18 V and 25°C
- Standardized, symmetrical output characteristics
- Noise margin (over full package temperature range)
 - 1 V at V_{DD} = 5 V 2 V at V_{DD} = 10 V
 - 2.5 V at VDD = 15 V
- 5-V, 10-V, and 15-V parametric ratings
- Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"



RECOMMENDED OPERATING CONDITIONS For maximum reliability, nominal operating con-

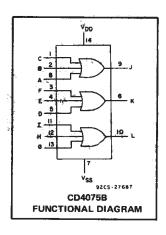
For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	LIN	UNITS	
	MIN.	MAX.	
Supply-Voltage Range (For TA = Full Package-Temperature Range)	3	18	٧



STATIC ELECTRICAL CHARACTERISTICS

CHARACTER-	CONDITIONS			LIMITS AT INDICATED TEMPERATURES (°C)						UNITS	
ISTIC	Vo	VIN	VDD				+25			UNITS	
	(V)	(V)	(V)	-55	40	+85	+125	Min.	Тур.	Max.	
Quiescent Device	-	0,5	5	0.25	0.25	7.5	7.5	_	0.01	0.25	
Current,		0,10	10	0.5	0,5	15	15	-	0.01	0,5	μА
IDD Max.	-	0,15	15	1	1	30	30	_	0.01	1	
	-	0,20	20	5	5	150	150	-	0.02	5	
Output Low	0.4	0,5	5	0.64	0.61	0.42	0.36	0.51	1	-	
(Sink) Current	0.5	0,10	10	1.6	1.5	1.1	0.9	1.3	2.6	-	
IOL Min.	1.5	0,15	15	4.2	4	2.8	2.4	3.4	6.8	_	
Output High	4.6	0,5	5	-0.64	-0.61	-0.42	-0.36	-0.51	-1	_	mA
(Source)	2.5	0,5	5	-2	-1.8	-1.3	-1.15	-1.6	-3.2	-	
Current, IOH Min.	9.5	0,10	10	-1.6	-1.5	-1.1	-0.9	-1.3	-2.6	-	
TOH WITH	13.5	0,15	15	-4.2	-4	-2.8	2.4	-3.4	-6.8	_	
Output Voltage:	_	0,5	5	0.05				0	0.05	٧	
Low-Level, VOL Max.	_	0,10	10	0.05				-	0		0.05
VUL 11118X.	_	0,15	15	0.05			_	0	0.05		
Output Voltage:		0,5	5	4.95			4.95	5	-		
High-Level,	_	0,10	10	9.95				9.95	10		-
VOH Min.	-	0,15	15	14.95			14.95	15	-		
Input Low	0.5, 4.5	1	. 5	1.5				_	Γ –	1.5	
Voltage, V _{IL} Max.	1, 9	_	10	3				_	_	3	
	1.5,13.5	+	15	4			_	_	4		
Input High Voltage, VIH Min.	4.5	1	5	3.5 3.5 — —				٧			
	9	, , ,	10	7				7			
	13.5	-	15	11				11	_,	-	
Input Current I _{IN} Max.	ii .	0,18	18	±0.1	±0.1	±1	±1	- :	±10 ⁻⁵	±0.1	μА



CD4071B, CD4072B, CD4075B Types

MAXIMUM RATINGS, Absolute-Maximum Values:	
DC SUPPLY-VOLTAGE RANGE, (V _{DD})	
Voltages referenced to V _{SS} Terminal)0.5V to	
INPUT VOLTAGE RANGE, ALL INPUTS0.5V to VDD	+0.5V
DC INPUT CURRENT, ANY ONE INPUT±	:10mA
POWER DISSIPATION PER PACKAGE (PD):	
For T _A = -55°C to +190°C 50	WmOC
For T _A = +100°C to +125°C	Wm00
DEVICE DISSIPATION PER OUTPUT TRANSISTOR	
FOR TA = FULL PACKAGE-TEMPERATURE RANGE (All Package Types)	00mW
OPERATING-TEMPERATURE RANGE (TA)55°C to +	125°C
STORAGE TEMPERATURE RANGE (Tstg)65°C to +	
LEAD TEMPERATURE (DURING SOLDERING):	
At distance 1/16 ± 1/32 inch (1.59 ± 0.79mm) from case for 10s max	265°C

DYNAMIC ELECTRICAL CHARACTERISTICS at T_A = 25°C, Input t_r, t_f = 20 ns, and C_L = 50 pF, R_L = 200 $\,k\Omega$

CHARACTERISTIC	TEST COND	TIONS	ALL LIN	UNITS	
		V _{DD} VOLTS	TYP.	MAX.	ONTS
Propagation Delay Time, tpHL, tpLH		5 10 15	125 60 45	250 120 90	ns
Transition Time, ^t THL ^{, t} TLH		5 10 15	100 50 40	200 100 80	ns
Input Capacitance, C _{IN}	Any Input	1 – 1	5	7.5	pF

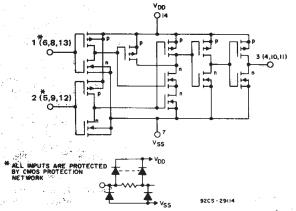


Fig. 3 - Schematic diagram for CD40718 (1 of 4 identical gates).

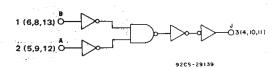


Fig. 5 -/ Logic diagram for CD4071B (1 of 4 identical gates).

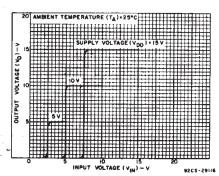


Fig. 1 — Typical voltage transfer characteristics

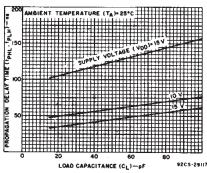


Fig. 2 — Typical propagation delay time as a function of load capacitance.

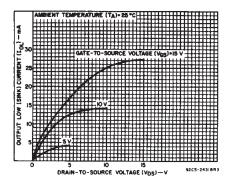


Fig. 4 — Typical output low (sink) current characteristics.

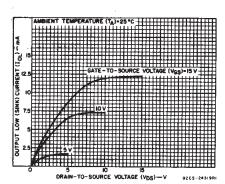
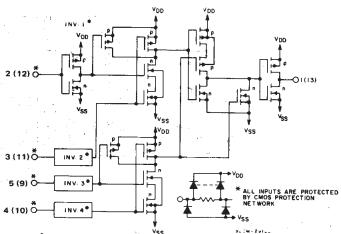


Fig. 6 — Minimum output low (sink) current characteristics.

CD4071B, CD4072B, CD4075B Types



INVERTERS 2,3 AND 4 ARE IDENTICAL TO INVERTER 1.

Fig. 7 - Schematic diagram for CD4072B (1 of 2 identical gates).

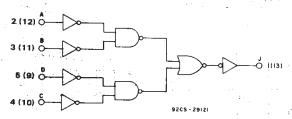


Fig. 9 - Logic diagram for CD4072B (1 of 2 identical gates).

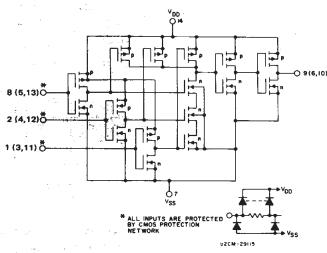


Fig. 11 - Schematic diagram for CD4075B (1 of 3 identical gates).

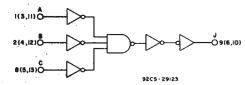


Fig. 13 - Logic diagram for CD4075B (1 of 3 identical gates).

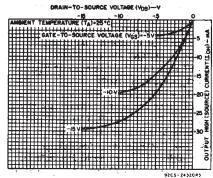


Fig. 8 — Typical output high (source) curren characteristics.

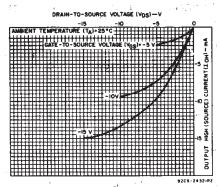


Fig. 10 – Minimum output high (source) current characteristics.

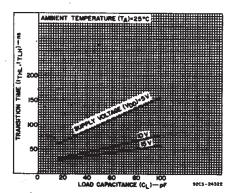


Fig. 12 - Typical transition time as a function of load capacitance.

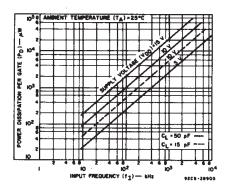
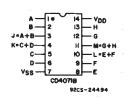
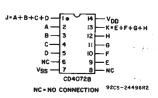


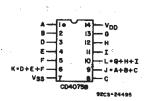
Fig. 14 — Typical dyanamic power dissipation as a function of frequency.

CD4071B, CD4072B, CD4075B Types

TERMINAL ASSIGNMENTS (TOP VIEW)







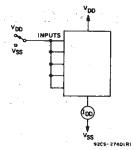


Fig. 15 - Quiescent device current test circuit.

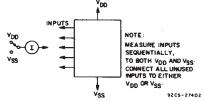


Fig. 16 - Input current test circuit.

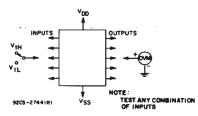
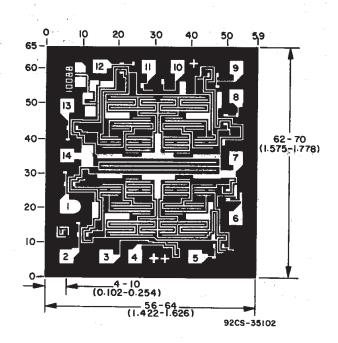
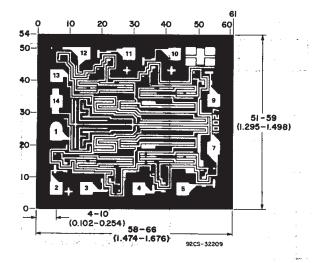


Fig. 17 - Input-voltage test circuit.

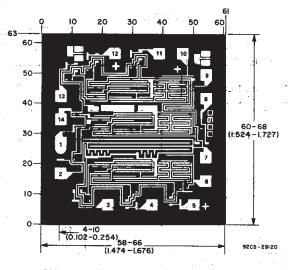
Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10⁻³ inch).



Chip dimensions and pad layout for CD4071B.



Chip dimensions and pad layout for CD4072B.



Chip dimensions and pad layout for CD4075B.

14 LEADS SHOWN



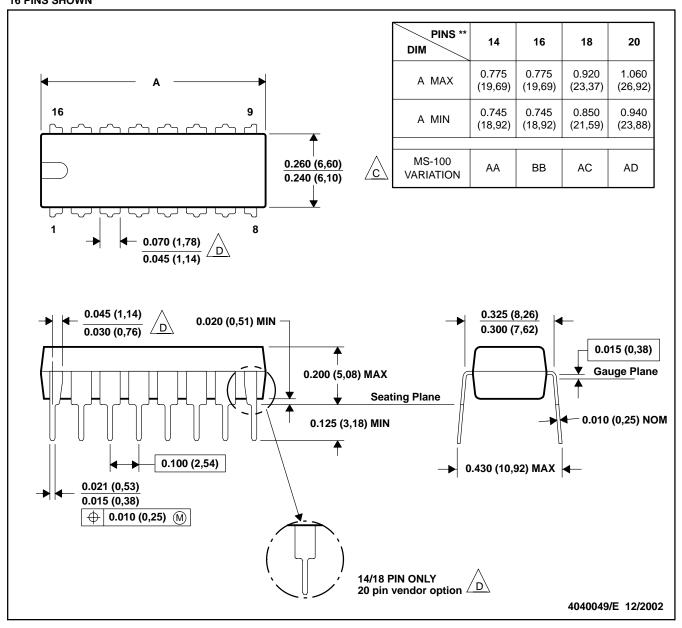
NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

16 PINS SHOWN

PLASTIC DUAL-IN-LINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

Falls within JEDEC MS-001, except 18 and 20 pin minimum body Irngth (Dim A).

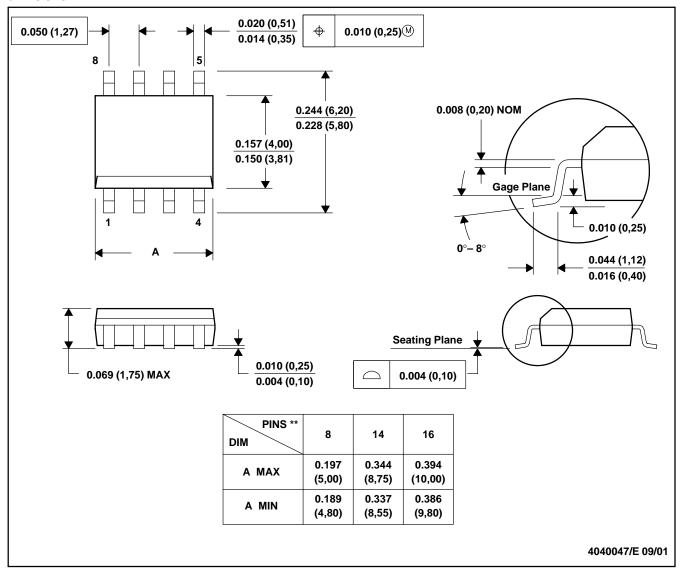
The 20 pin end lead shoulder width is a vendor option, either half or full width.

1

D (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

8 PINS SHOWN



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-012

MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

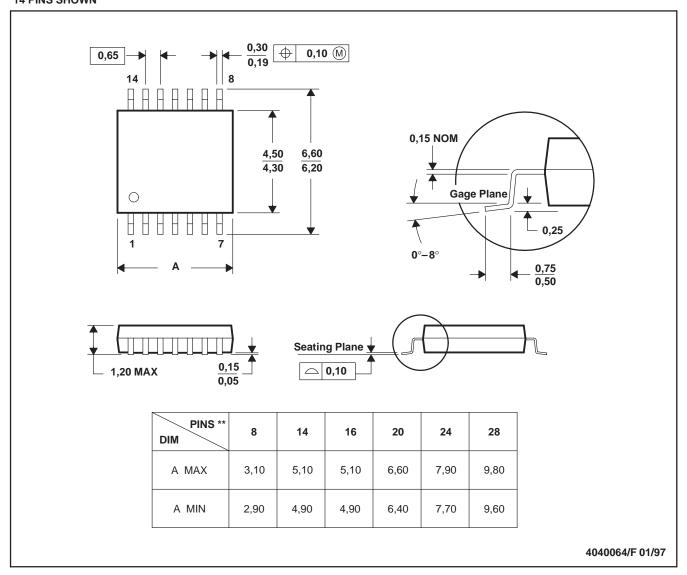
- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



PW (R-PDSO-G**)

14 PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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